International
IOR Rectifier

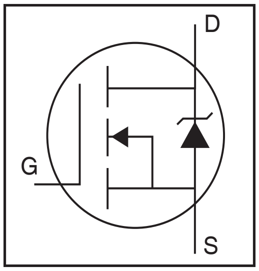
AUTOMOTIVE GRADE

PD - 96395A

AUIRFS3107-7P

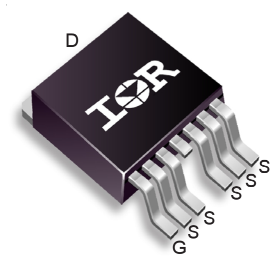
HEXFET® Power MOSFET

Features
- Advanced Process Technology
- Ultra Low On-Resistance
- Enhanced dV/dT and dI/dT capability
- 175°C Operating Temperature
- Fast Switching
- Repetitive Avalanche Allowed up to Tjmax
- Lead-Free, RoHS Compliant
- Automotive Qualified *



V_{DSS}		75V
$R_{DS(on)}$	typ.	2.1mΩ
	max.	2.6mΩ
I_D (Silicon Limited)		260A①
I_D (Package Limited)		240A

Description
Specifically designed for Automotive applications, this HEXFET® Power MOSFET utilizes the latest processing techniques to achieve extremely low on-resistance per silicon area. Additional features of this design are a 175°C junction operating temperature, fast switching speed and improved repetitive avalanche rating . These features combine to make this design an extremely efficient and reliable device for use in Automotive applications and a wide variety of other applications.



D^2Pak 7 Pin
AUIRFS3107-7P

G	D	S
Gate	Drain	Source

Absolute Maximum Ratings
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only; and functional operation of the device at these or any other condition beyond those indicated in the specifications is not implied.Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions. Ambient temperature (T_A) is 25°C, unless otherwise specified.

	Parameter	Max.	Units
I_D @ T_C = 25°C	Continuous Drain Current, V_{GS} @ 10V (Silicon Limited)	260①	A
I_D @ T_C = 100°C	Continuous Drain Current, VGS @ 10V (Silicon Limited)	190	
I_D @ T_C = 25°C	Continuous Drain Current, V_{GS} @ 10V (Package Limited)	240	
I_{DM}	Pulsed Drain Current ②	1060	
P_D @T_C = 25°C	Maximum Power Dissipation	370	W
	Linear Derating Factor	2.5	W/°C
V_{GS}	Gate-to-Source Voltage	± 20	V
E_{AS}	Single Pulse Avalanche Energy (Thermally Limited) ③	320	mJ
I_{AR}	Avalanche Current ②	See Fig. 14, 15, 22a, 22b	A
E_{AR}	Repetitive Avalanche Energy ②		mJ
dv/dt	Peak Diode Recovery ④	13	V/ns
T_J T_{STG}	Operating Junction and Storage Temperature Range	-55 to + 175	°C
	Soldering Temperature, for 10 seconds (1.6mm from case)	300	

Thermal Resistance

	Parameter	Typ.	Max.	Units
$R_{\theta JC}$	Junction-to-Case ⑨⑩	——	0.40	°C/W
$R_{\theta JA}$	Junction-to-Ambient (PCB Mount) ⑧	——	40	

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*Qualification standards can be found at http://www.irf.com/

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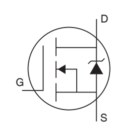
Static Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Typ.	Max.	Units	Conditions
$V_{(BR)DSS}$	Drain-to-Source Breakdown Voltage	75	——	——	V	V_{GS} = 0V, I_D = 250μA
$\Delta V_{(BR)DSS}/\Delta T_J$	Breakdown Voltage Temp. Coefficient	——	0.083	——	V/°C	Reference to 25°C, I_D = 5mA②
$R_{DS(on)}$	Static Drain-to-Source On-Resistance	——	2.1	2.6	mΩ	V_{GS} = 10V, I_D = 160A ⑤
$V_{GS(th)}$	Gate Threshold Voltage	2.0	——	4.0	V	V_{DS} = V_{GS}, I_D = 250μA
gfs	Forward Transconductance	260	——	——	S	V_{DS} = 25V, I_D = 160A
R_G	Internal Gate Resistance	——	2.1	——	Ω	
I_{DSS}	Drain-to-Source Leakage Current	——	——	20	μA	V_{DS} = 75V, V_{GS} = 0V
		——	——	250		V_{DS} = 75V, V_{GS} = 0V, T_J = 125°C
I_{GSS}	Gate-to-Source Forward Leakage	——	——	100	nA	V_{GS} = 20V
	Gate-to-Source Reverse Leakage	——	——	-100		V_{GS} = -20V

Dynamic Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Typ.	Max.	Units	Conditions
Q_g	Total Gate Charge	——	160	240	nC	I_D = 160A
Q_{gs}	Gate-to-Source Charge	——	38	——		V_{DS} = 38V
Q_{gd}	Gate-to-Drain ("Miller") Charge	——	57	——		V_{GS} = 10V ⑤
Q_{sync}	Total Gate Charge Sync. (Q_g - Q_{gd})	——	103	——		I_D = 160A, V_{DS} =0V, V_{GS} = 10V
$t_{d(on)}$	Turn-On Delay Time	——	17	——	ns	V_{DD} = 49V
t_r	Rise Time	——	80	——		I_D = 160A
$t_{d(off)}$	Turn-Off Delay Time	——	100	——		R_G = 2.7Ω
t_f	Fall Time	——	64	——		V_{GS} = 10V ⑤
C_{iss}	Input Capacitance	——	9200	——	pF	V_{GS} = 0V
C_{oss}	Output Capacitance	——	850	——		V_{DS} = 50V
C_{rss}	Reverse Transfer Capacitance	——	400	——		f = 1.0MHz
C_{oss} eff. (ER)	Effective Output Capacitance (Energy Related)⑦	——	1150	——		V_{GS} = 0V, V_{DS} = 0V to 60V ⑦
C_{oss} eff. (TR)	Effective Output Capacitance (Time Related)⑥	——	1500	——		V_{GS} = 0V, V_{DS} = 0V to 60V ⑥

Diode Characteristics

	Parameter	Min.	Typ.	Max.	Units	Conditions	
I_S	Continuous Source Current (Body Diode)	——	——	260①	A	MOSFET symbol showing the integral reverse p-n junction diode. 	
I_{SM}	Pulsed Source Current (Body Diode) ②	——	——	1060			
V_{SD}	Diode Forward Voltage	——	——	1.3	V	T_J = 25°C, I_S = 160A, V_{GS} = 0V ⑤	
t_{rr}	Reverse Recovery Time	——	52	——	ns	T_J = 25°C	V_R = 64V,
		——	63	——		T_J = 125°C	I_F = 160A
Q_{rr}	Reverse Recovery Charge	——	110	——	nC	T_J = 25°C	di/dt = 100A/μs ⑤
		——	160	——		T_J = 125°C	
I_{RRM}	Reverse Recovery Current	——	3.8	——	A	T_J = 25°C	
t_{on}	Forward Turn-On Time	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)					

Notes:

① Calculated continuous current based on maximum allowable junction temperature. Bond wire current limit is 240A. Note that current limitations arising from heating of the device leads may occur with some lead mounting arrangements.

② Repetitive rating; pulse width limited by max. junction temperature.

③ Limited by T_{Jmax}, starting T_J = 25°C, L = 0.026mH R_G = 25Ω, I_{AS} = 160A, V_{GS} =10V. Part not recommended for use above this value .

④ $I_{SD} \leq$ 160A, di/dt ≤ 1420A/μs, $V_{DD} \leq V_{(BR)DSS}$, $T_J \leq$ 175°C.

⑤ Pulse width ≤ 400μs; duty cycle ≤ 2%.

⑥ C_{oss} eff. (TR) is a fixed capacitance that gives the same charging time as C_{oss} while V_{DS} is rising from 0 to 80% V_{DSS}.

⑦ C_{oss} eff. (ER) is a fixed capacitance that gives the same energy as C_{oss} while V_{DS} is rising from 0 to 80% V_{DSS}.

⑧ When mounted on 1" square PCB (FR-4 or G-10 Material). For recom mended footprint and soldering echniques refer to application note #AN-994.

⑨ R_θ is measured at T_J approximately 90°C.

⑩ $R_{\theta JC}$ value shown is at time zero.

Qualification Information†

Qualification Level		Automotive (per AEC-Q101) ††	
		Comments: This part number(s) passed Automotive qualification. IR's Industrial and Consumer qualification level is granted by extension of the higher Automotive level.	
Moisture Sensitivity Level		7L-D^2PAK	MSL1
ESD	Machine Model	Class M4(+/- 800V)††† (per AEC-Q101-002)	
	Human Body Model	Class H3A(+/- 6000V)††† (per AEC-Q101-001)	
	Charged Device Model	Class C5(+/- 2000V)††† (per AEC-Q101-005)	
RoHS Compliant		Yes	

† Qualification standards can be found at International Rectifier's web site: http//www.irf.com/

†† Exceptions (if any) to AEC-Q101 requirements are noted in the qualification report.

††† Highest passing voltage

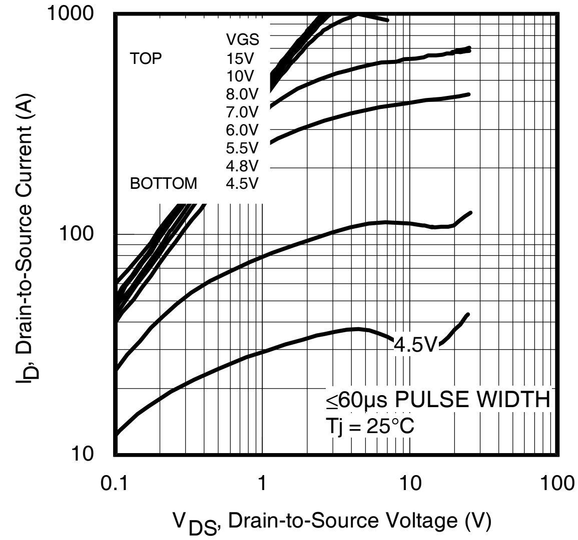


Fig 1. Typical Output Characteristics

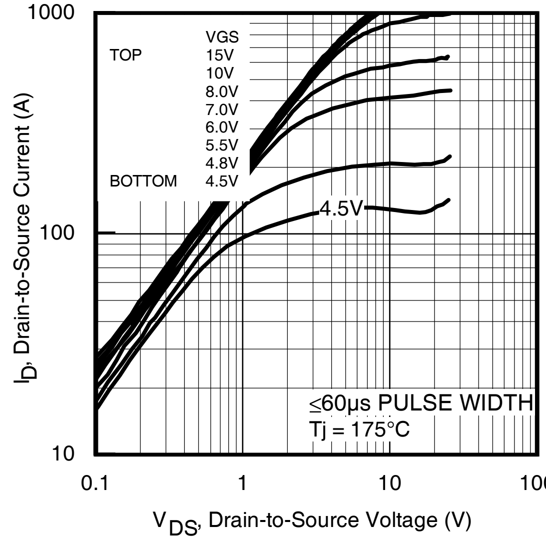


Fig 2. Typical Output Characteristics

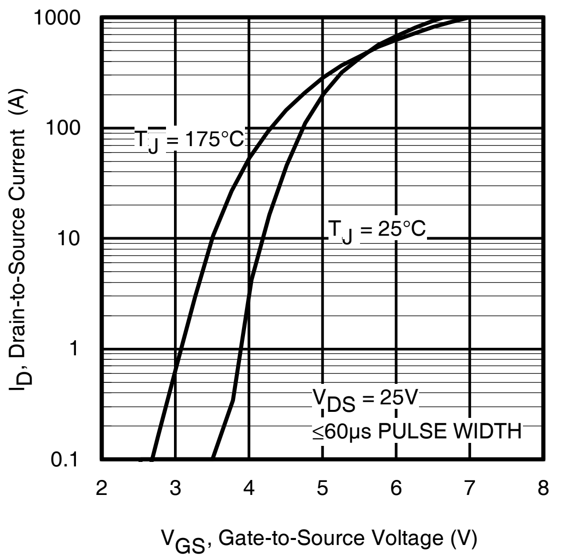


Fig 3. Typical Transfer Characteristics

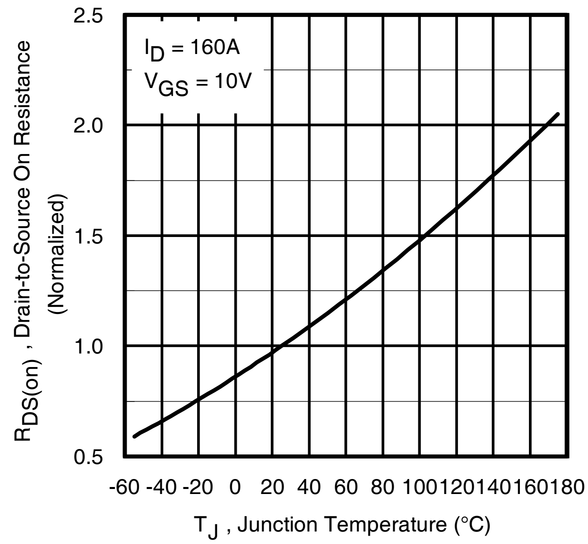


Fig 4. Normalized On-Resistance vs. Temperature

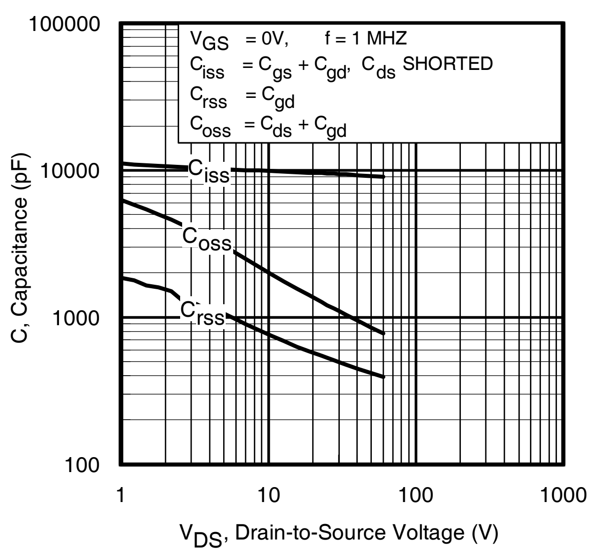


Fig 5. Typical Capacitance vs. Drain-to-Source Voltage

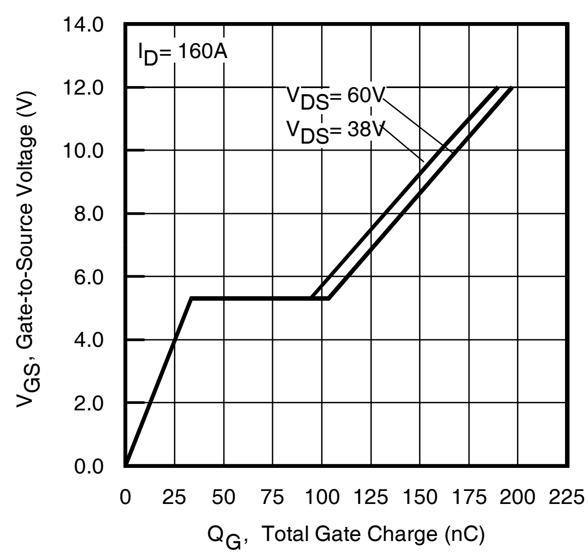


Fig 6. Typical Gate Charge vs. Gate-to-Source Voltage

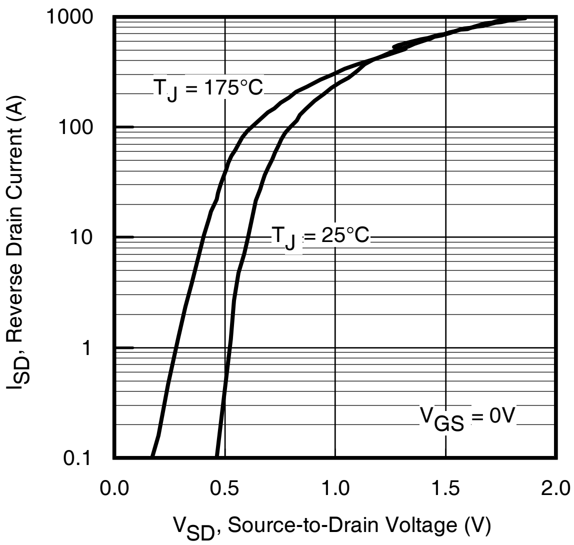


Fig 7. Typical Source-Drain Diode Forward Voltage

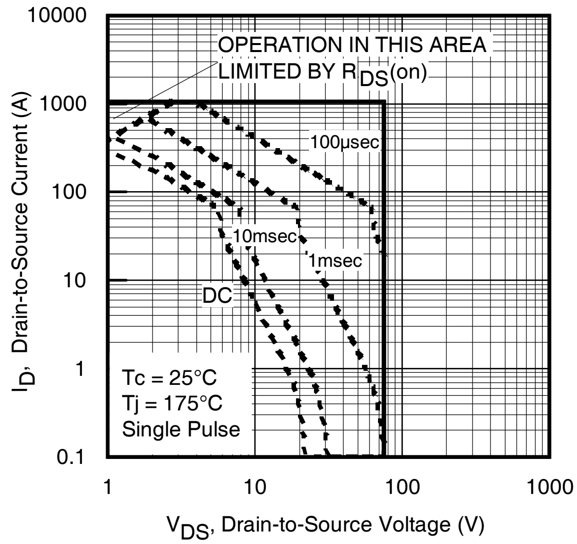


Fig 8. Maximum Safe Operating Area

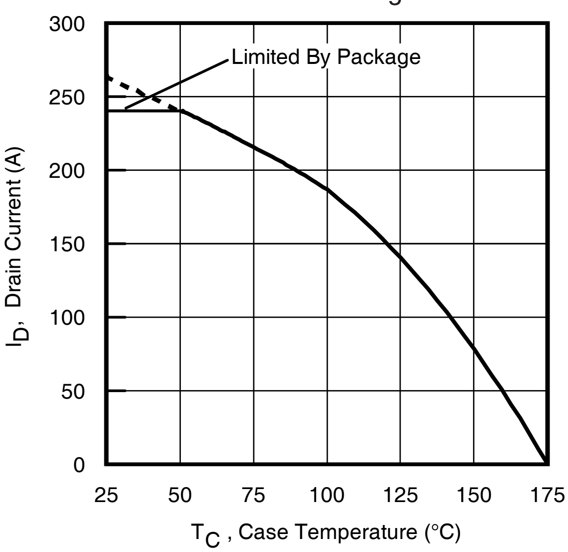


Fig 9. Maximum Drain Current vs. Case Temperature

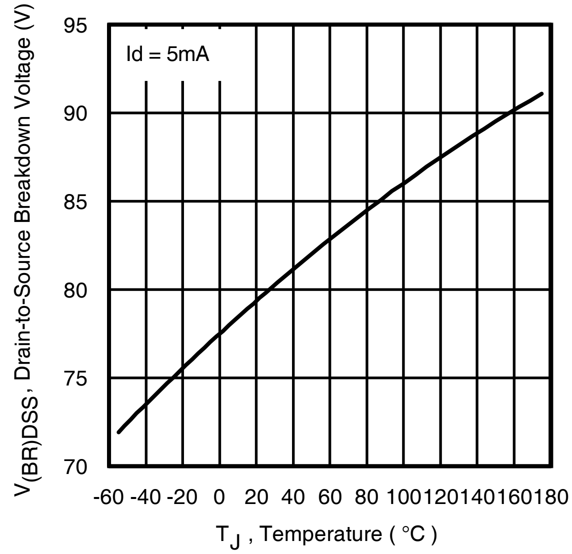


Fig 10. Drain-to-Source Breakdown Voltage

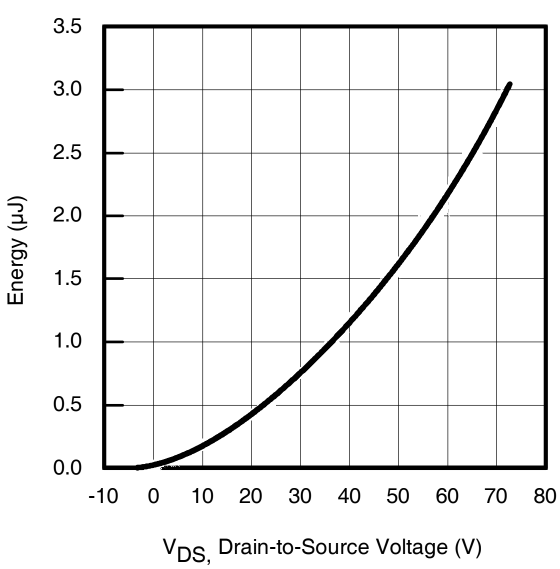


Fig 11. Typical C_{OSS} Stored Energy

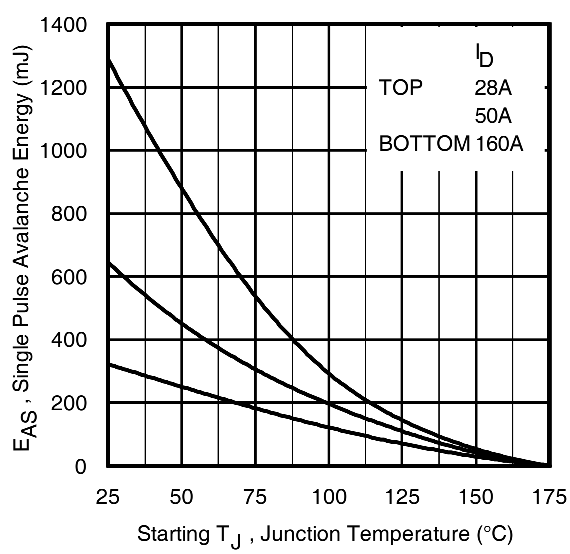
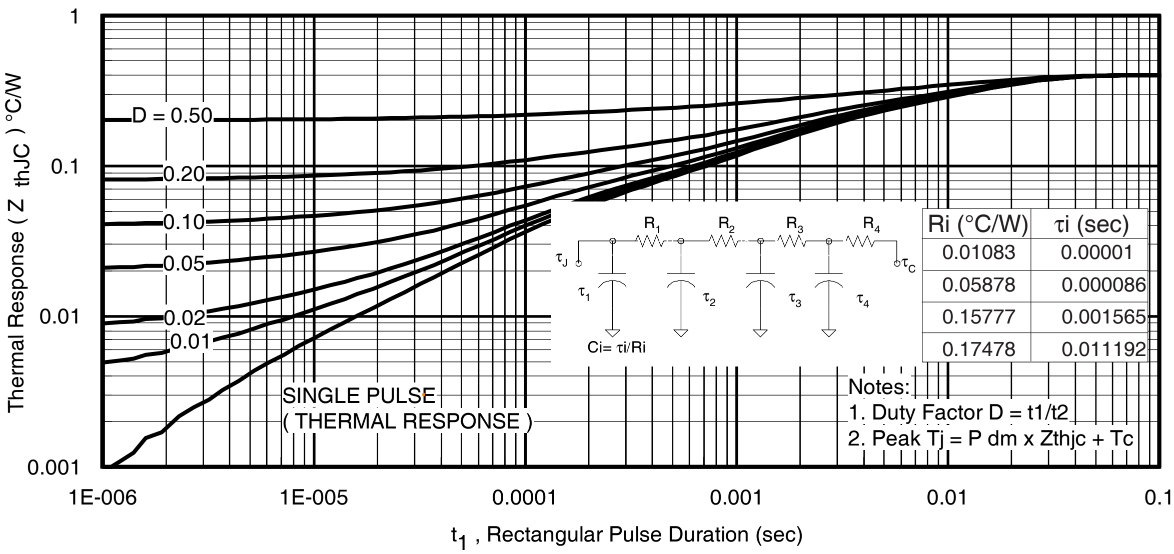


Fig 12. Maximum Avalanche Energy vs. DrainCurrent



Ri (°C/W)	τi (sec)
0.01083	0.00001
0.05878	0.000086
0.15777	0.001565
0.17478	0.011192

Fig 13. Maximum Effective Transient Thermal Impedance, Junction-to-Case

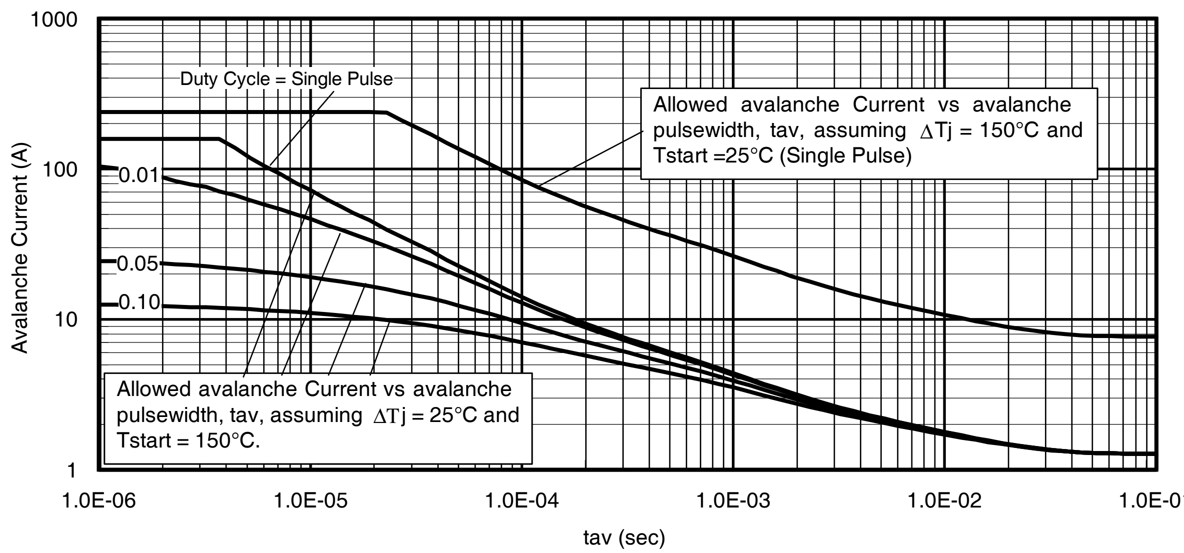


Fig 14. Typical Avalanche Current vs.Pulsewidth

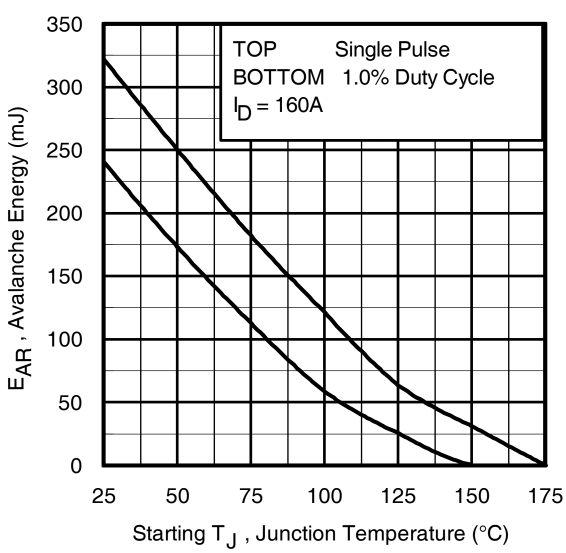


Fig 15. Maximum Avalanche Energy vs. Temperature

Notes on Repetitive Avalanche Curves , Figures 14, 15:
(For further info, see AN-1005 at www.irf.com)

1. Avalanche failures assumption:
   Purely a thermal phenomenon and failure occurs at a temperature far in excess of T_{jmax}. This is validated for every part type.
2. Safe operation in Avalanche is allowed as long as T_{jmax} is not exceeded.
3. Equation below based on circuit and waveforms shown in Figures 22a, 22b.
4. $P_{D\ (ave)}$ = Average power dissipation per single avalanche pulse.
5. BV = Rated breakdown voltage (1.3 factor accounts for voltage increase during avalanche).
6. I_{av} = Allowable avalanche current.
7. ΔT = Allowable rise in junction temperature, not to exceed T_{jmax} (assumed as 25°C in Figure 14, 15).
   t_{av} = Average time in avalanche.
   D = Duty cycle in avalanche = $t_{av} \cdot f$
   $Z_{thJC}(D, t_{av})$ = Transient thermal resistance, see Figures 13)

$$P_{D\ (ave)} = 1/2\ (1.3 \cdot BV \cdot I_{av}) = \Delta T / Z_{thJC}$$
$$I_{av} = 2\Delta T / [1.3 \cdot BV \cdot Z_{th}]$$
$$E_{AS\ (AR)} = P_{D\ (ave)} \cdot t_{av}$$

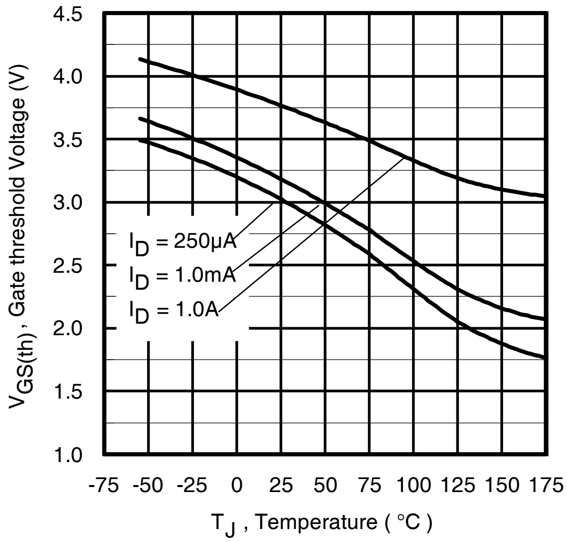


Fig 16. Threshold Voltage vs. Temperature

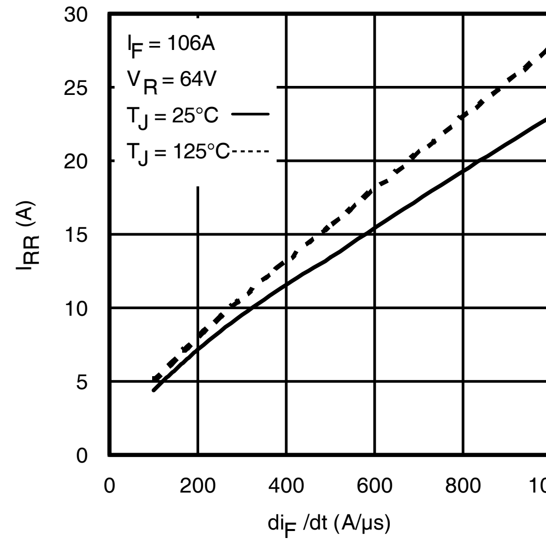


Fig. 17 - Typical Recovery Current vs. di_f/dt

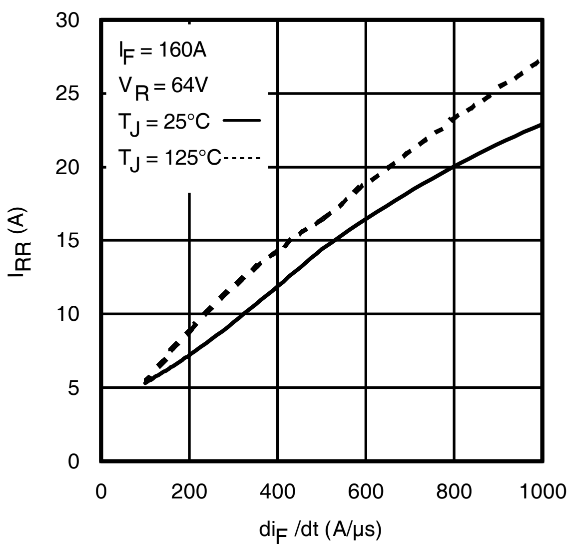


Fig. 18 - Typical Recovery Current vs. di_f/dt

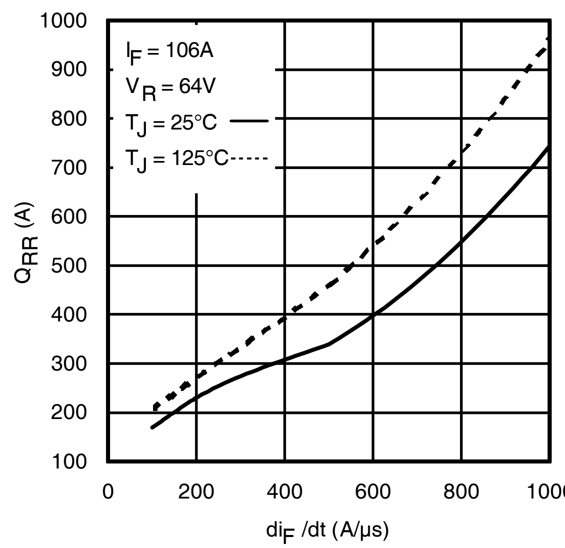


Fig. 19 - Typical Stored Charge vs. di_f/dt

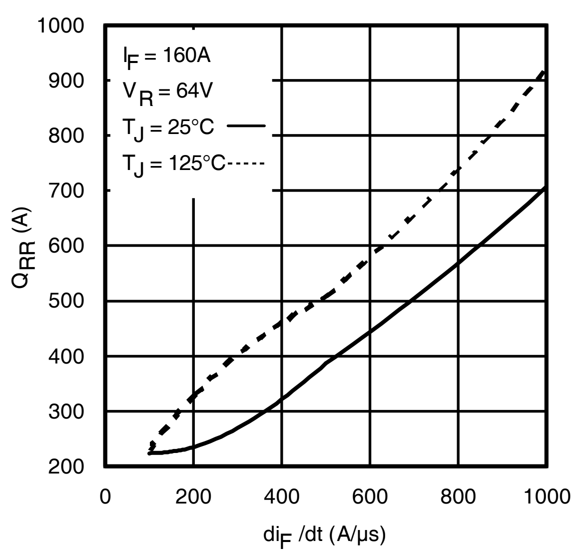
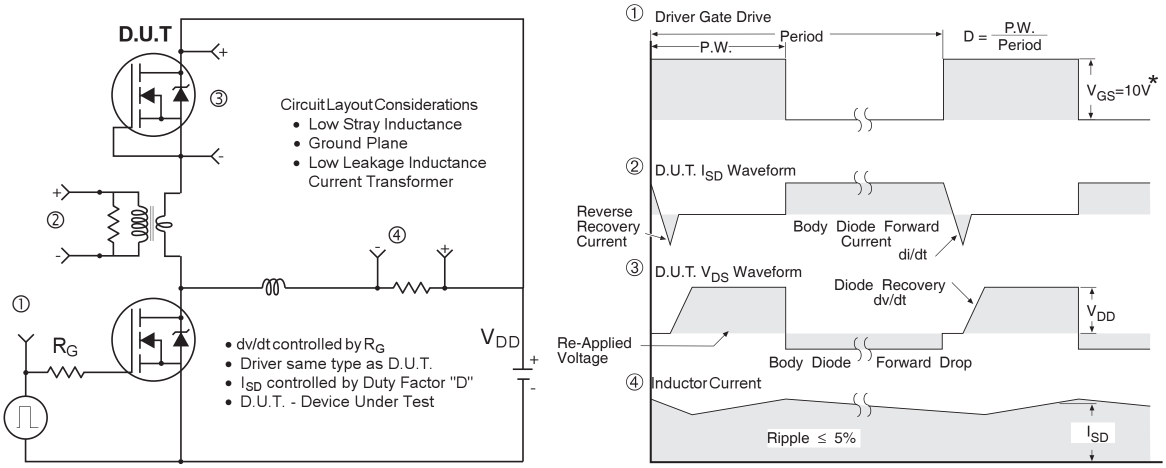


Fig. 20 - Typical Stored Charge vs. di_f/dt



* V_{GS} = 5V for Logic Level Devices

Fig 21. Peak Diode Recovery dv/dt Test Circuit for N-Channel HEXFET® Power MOSFETs

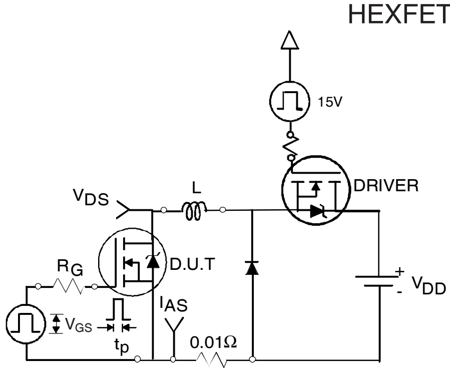


Fig 22a. Unclamped Inductive Test Circuit

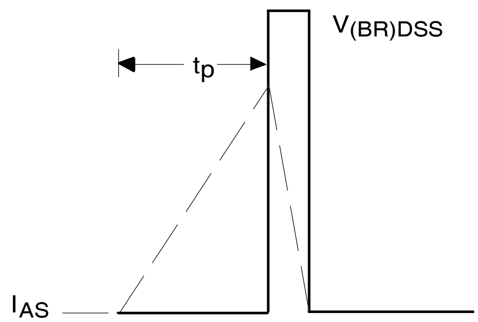


Fig 22b. Unclamped Inductive Waveforms

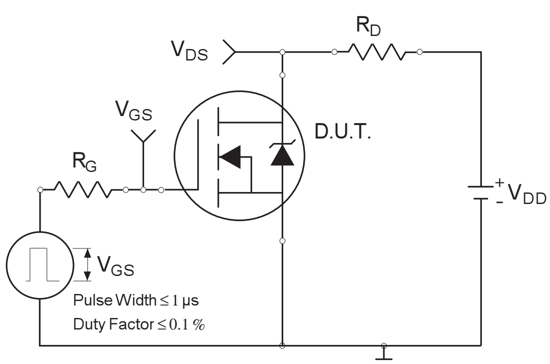


Fig 23a. Switching Time Test Circuit

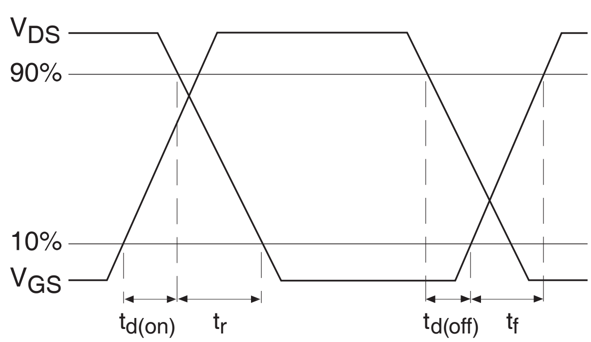


Fig 23b. Switching Time Waveforms

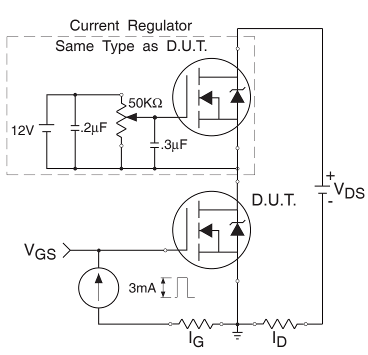


Fig 24a. Gate Charge Test Circuit

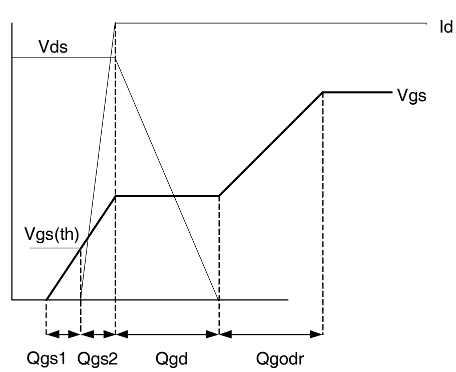
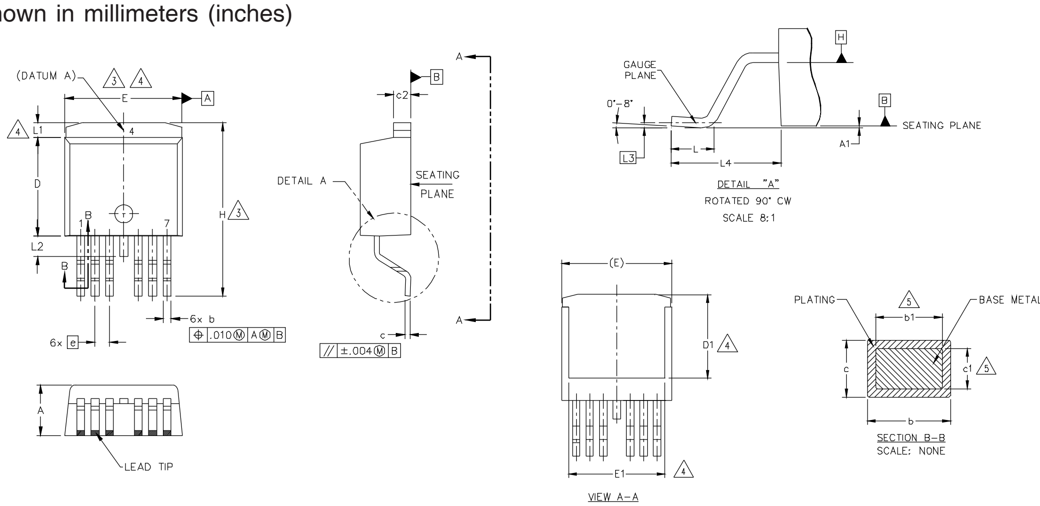


Fig 24b. Gate Charge Waveform

D^2Pak - 7 Pin Package Outline

Dimensions are shown in millimeters (inches)

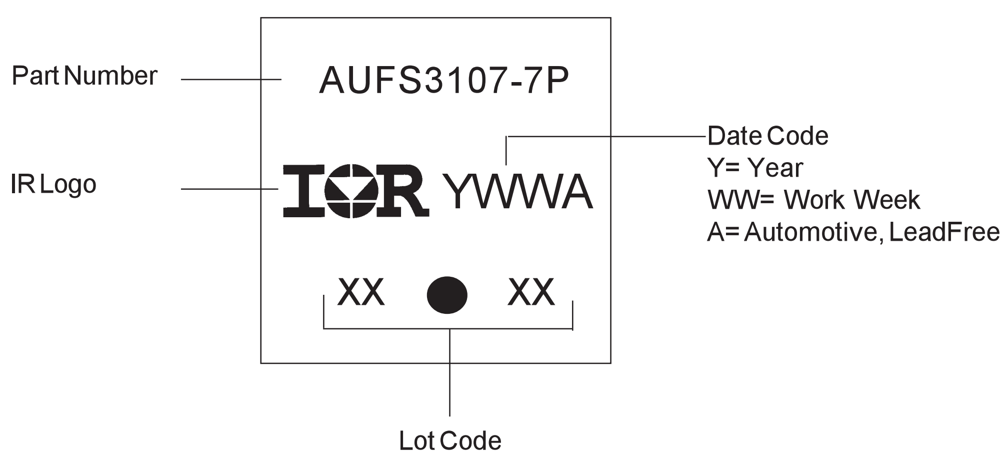


SYMBOL	DIMENSIONS MILLIMETERS MIN.	MILLIMETERS MAX.	INCHES MIN.	INCHES MAX.	NOTES
A	4.06	4.83	.160	.190	
A1	–	0.254	–	.010	
b	0.51	0.99	.020	.036	
b1	0.51	0.89	.020	.032	5
c	0.38	0.74	.015	.029	
c1	0.38	0.58	.015	.023	5
c2	1.14	1.65	.045	.065	
D	8.38	9.65	.330	.380	3
D1	6.86	–	.270		4
E	9.65	10.67	.380	.420	3,4
E1	6.22	–	.245		4
e	1.27 BSC		.050 BSC		
H	14.61	15.88	.575	.625	
L	1.78	2.79	.070	.110	
L1	–	1.68	–	.066	4
L2	–	1.78	–	.070	
L3	0.25 BSC		.010 BSC		
L4	4.78	5.28	.188	.208	

NOTES:

1. DIMENSIONING AND TOLERANCING AS PER ASME Y14.5M-1994
2. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].
3. DIMENSION D & E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.127 [.005"] PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTMOST EXTREMES OF THE PLASTIC BODY AT DATUM H.
4. THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSION E, L1, D1 & E1.
5. DIMENSION b1 AND c1 APPLY TO BASE METAL ONLY.
6. DATUM A & B TO BE DETERMINED AT DATUM PLANE H.
7. CONTROLLING DIMENSION: INCH.
8. OUTLINE CONFORMS TO JEDEC OUTLINE TO-263CB.

D^2Pak - 7 Pin Part Marking Information



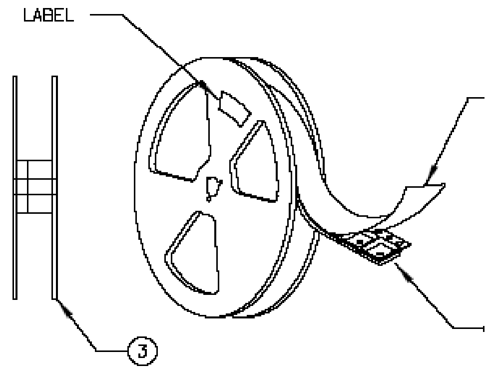
Note: For the most current drawing please refer to IR website at http://www.irf.com/package/

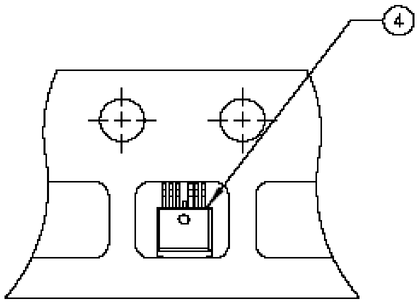
D2Pak - 7 Pin Tape and Reel

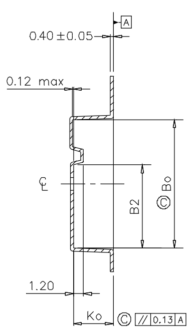
NOTES, TAPE & REEL, LABELLING:

1. TAPE AND REEL.
   - 1.1 REEL SIZE 13 INCH DIAMETER.
   - 1.2 EACH REEL CONTAINING 800 DEVICES.
   - 1.3 THERE SHALL BE A MINIMUM OF 42 SEALED POCKETS CONTAINED IN THE LEADER AND A MINIMUM OF 15 SEALED POCKETS IN THE TRAILER.
   - 1.4 PEEL STRENGTH MUST CONFORM TO THE SPEC. NO. 71-9667.
   - 1.5 PART ORIENTATION SHALL BE AS SHOWN BELOW.
   - 1.6 REEL MAY CONTAIN A MAXIMUM OF TWO UNIQUE LOT CODE/DATE CODE COMBINATIONS. REWORKED REELS MAY CONTAIN A MAXIMUM OF THREE UNIQUE LOT CODE/DATE CODE COMBINATIONS. HOWEVER, THE LOT CODES AND DATE CODES WITH THEIR RESPECTIVE QUANTITIES SHALL APPEAR ON THE BAR CODE LABEL FOR THE AFFECTED REEL.

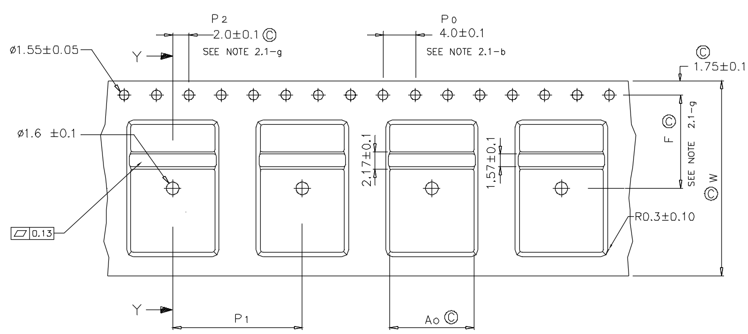
2. LABELLING (REEL AND SHIPPING BAG).
   - 2.1 CUST. PART NUMBER (BAR CODE): IRF2804S-7PTRL
   - 2.2 CUST. PART NUMBER (TEXT CODE): IRF2804S-7PTRL
   - 2.3 I.R. PART NUMBER: IRF2804S-7PTRL
   - 2.4 QUANTITY:
   - 2.5 VENDOR CODE: IR
   - 2.6 LOT CODE:
   - 2.7 DATE CODE:





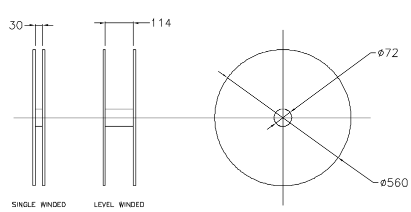


SECTION Y-Y



CARRIER TAPE

Ao	10.80	+/- 0.1
Bo	16.00	+/- 0.1
B2	10.35	+/- 0.1
Ko	4.90	+/- 0.1
F	11.50	+/- 0.1
P1	16.00	+/- 0.1
W	24.00	+/- 0.1



REEL
SCALE: 1:40

LONG	UNITS
130	METERS/REEL

Note: For the most current drawing please refer to IR website at http://www.irf.com/package/

Ordering Information

Base part	Package Type	Standard Pack		Complete Part Number
		Form	Quantity	
AUIRFS3107-7P	D2Pak -7Pin	Tube	75	AUIRFS3107-7P
		Tape and Reel Left	800	AUIRFS3107-7TRL
		Tape and Reel Right	800	AUIRFS3107-7TRR

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http://www.irf.com/technical-info/

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